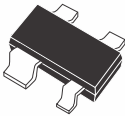


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## BAS56

### DUAL HIGH CURRENT SWITCHING DIODE



SOT-143 CASE

**Central**  
Semiconductor Corp.

#### DESCRIPTION:

The CENTRAL SEMICONDUCTOR BAS56 type is an ultra-high speed silicon switching diode manufactured by the epitaxial planar process, in an epoxy molded surface mount package with isolated dual diodes, designed for high current, high speed switching applications.

Marking code is L51.

#### MAXIMUM RATINGS (T<sub>A</sub>=25°C)

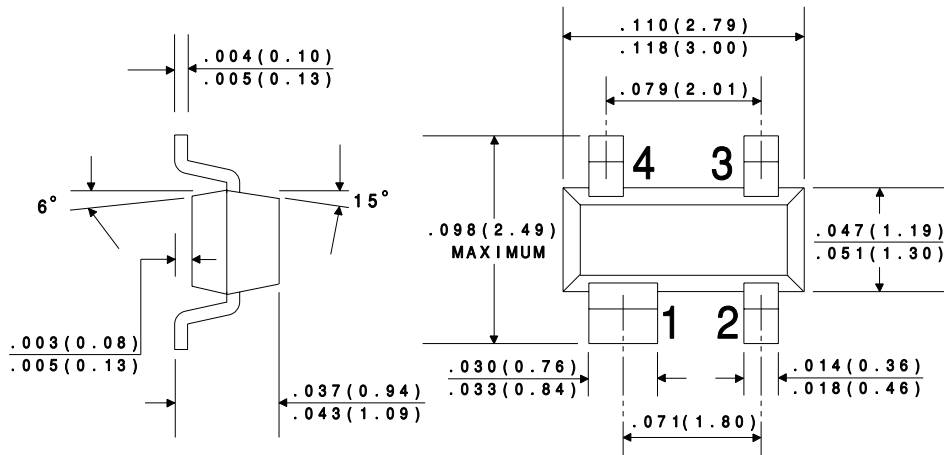
|                                                | SYMBOL                            |             | UNITS |
|------------------------------------------------|-----------------------------------|-------------|-------|
| Continuous Reverse Voltage                     | V <sub>R</sub>                    | 60          | V     |
| Peak Repetitive Reverse Voltage                | V <sub>RRM</sub>                  | 60          | V     |
| Continuous Forward Current                     | I <sub>F</sub>                    | 200         | mA    |
| Peak Repetitive Forward Current                | I <sub>FRM</sub>                  | 600         | mA    |
| Forward Surge Current, t <sub>p</sub> =1 μsec. | I <sub>FSM</sub>                  | 4000        | mA    |
| Forward Surge Current, t <sub>p</sub> =1 sec.  | I <sub>FSM</sub>                  | 1000        | mA    |
| Power Dissipation                              | P <sub>D</sub>                    | 350         | mW    |
| Operating and Storage                          |                                   |             |       |
| Junction Temperature                           | T <sub>J</sub> , T <sub>stg</sub> | -65 to +150 | °C    |
| Thermal Resistance                             | θ <sub>JA</sub>                   | 357         | °C/W  |

#### ELECTRICAL CHARACTERISTICS (T<sub>A</sub>=25°C unless otherwise noted)

| SYMBOL          | TEST CONDITIONS                                                           | MIN | MAX  | UNITS |
|-----------------|---------------------------------------------------------------------------|-----|------|-------|
| I <sub>R</sub>  | V <sub>R</sub> =60V                                                       |     | 100  | nA    |
| I <sub>R</sub>  | V <sub>R</sub> =60V, T <sub>A</sub> =150°C                                |     | 100  | μA    |
| I <sub>R</sub>  | V <sub>R</sub> =75V                                                       |     | 10   | μA    |
| V <sub>F</sub>  | I <sub>F</sub> =10mA                                                      |     | 0.75 | V     |
| V <sub>F</sub>  | I <sub>F</sub> =200mA                                                     |     | 1.00 | V     |
| V <sub>F</sub>  | I <sub>F</sub> =500mA                                                     |     | 1.25 | V     |
| C <sub>T</sub>  | V <sub>R</sub> =0, f=1 MHz                                                |     | 2.5  | pF    |
| t <sub>rr</sub> | I <sub>F</sub> =I <sub>R</sub> =400mA, R <sub>L</sub> =100Ω, Rec. to 40mA |     | 6.0  | ns    |
| Q <sub>s</sub>  | I <sub>F</sub> =10mA, V <sub>R</sub> =5.0V, R <sub>L</sub> =500Ω          |     | 50   | pC    |
| V <sub>FB</sub> | I <sub>F</sub> =400mA, t <sub>r</sub> =30ns                               |     | 1.2  | V     |
| V <sub>FR</sub> | I <sub>F</sub> =400mA, t <sub>r</sub> =100ns                              |     | 1.5  | V     |



All dimensions in inches (mm).



LEAD CODE:

- 1) ANODE 1
- 2) ANODE 2
- 3) CATHODE 2
- 4) CATHODE 1